

Secondary LDO Regulators

Secondary Variable Output LDO Regulator



BD00IA5WEFJ

No.10026EAT10

●Description

BD00IA5WEFJ is a LDO regulator with output current 0.5A. The output accuracy is $\pm 1\%$ of output voltage. With external resistance, it is available to set the output voltage at random (from 0.8V to 5.5V) and also provides output voltage fixed type without external resistance. It is used for the wide applications of digital appliances. It has package type: HTSOP-J8. Over current protection (for protecting the IC destruction by output short circuit), circuit current ON/OFF switch (for setting the circuit 0 μ A at shutdown mode), and thermal shutdown circuit (for protecting IC from heat destruction by over load condition) are all built in. It is usable for ceramic capacitor and enables to improve smaller set and long-life.

●Features

- 1) Output current 0.5A
- 2) High accuracy reference voltage circuit
- 3) Built-in Over Current Protection circuit (OCP)
- 4) Built-in Thermal Shut Down circuit (TSD)
- 5) With shut down switch
- 6) Output voltage variable type (0.8V to 4.5V)
- 7) Package: HTSOP-J8

●Output voltage differential Line up

Product name	Variable	Package
BD00IA5WEFJ	O	HTSOP-J8

Product name : B D 0 0 I C 0 W E F J

a
b
c
d
e

Signal	Description			
a	Output voltage (V)			
	00		Variable	
b	Voltage resistance(V)			
	E	24V	H	10V
	F	20V	I	7V
	G	15V		
c	Output current (A)			
	A1	0.1A	C0	1.0A
	A3	0.3A	C5	1.5A
	A5	0.5A	D0	2.0A
d	Shutdown switch			
	“W”		Shutdown switch is built in	
	“ ”		Shutdown switch is not built in	
e	Package			
	EFJ		HTSOP-J8	

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Power supply voltage	V _{CC}	7.0 ^{*1}	V
EN voltage	V _{EN}	7.0	V
Output voltage	V _{OUT}	7.0	V
Feedback voltage	V _{FB}	7.0	V
Power dissipation	HTSOP-J8 Pd ^{*2}	2110 ^{*2}	mW
Operating Temperature Range	Topr	-25~+85	°C
Storage Temperature Range	Tstg	-55~+150	°C
Junction Temperature	Tjmax	+150	°C

*1 Not to exceed Pd

*2 Reduced by 16.9mW/°C for each increase in Ta of 1°C over 25°C. (when mounted on a board 70mm × 70mm × 1.6mm glass-epoxy board, two layer)

●Operating conditions (Ta=25°C)

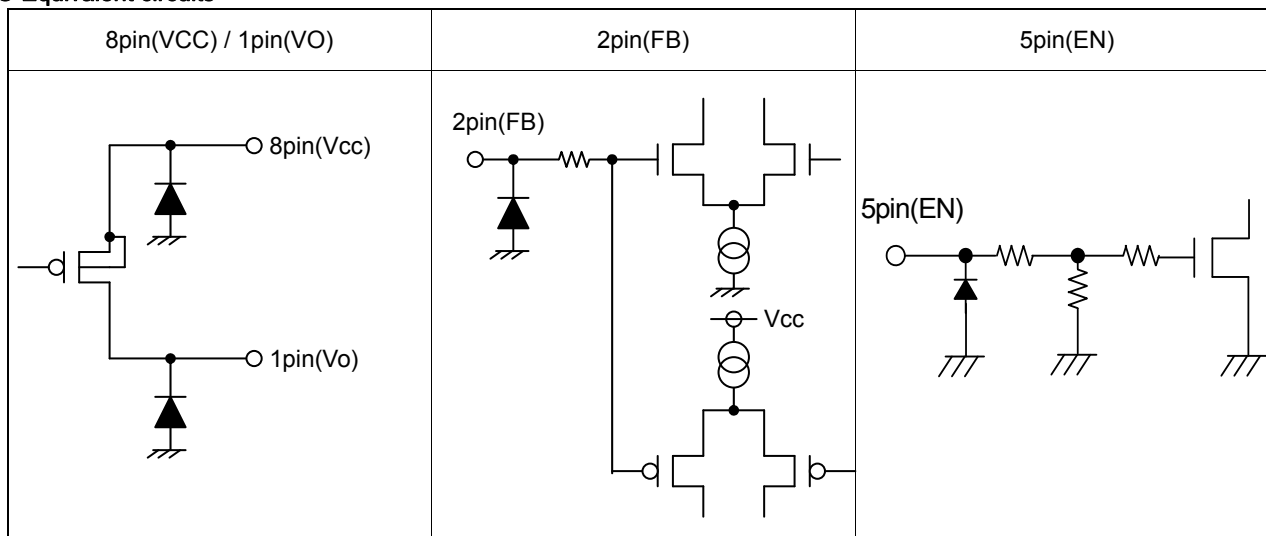
Parameter	Symbol	Ratings		Unit
		Min.	Max.	
Input power supply voltage	V _{CC}	2.4	5.5	V
EN voltage	V _{EN}	0.0	5.5	V
Output voltage setting range	V _O	0.8	4.5	V
Output current	I _O	0.0	0.5	A

This product should not be used in a radioactive environment.

●Electrical characteristics (Unless otherwise noted, Ta=25°C, EN=3V, V_{CC}=3.3V, R₁=16kΩ, R₂=7.5kΩ)

Parameter	Symbol	Limits			Unit	Conditions
		Min.	Typ.	Max.		
Circuit current at shutdown mode	I _{sd}	-	0	5	μA	EN=0V, OFF mode
Bias current	I _{CC}	-	250	500	μA	
Line regulation	Reg.I	-	25	50	mV	V _{CC} =(V _O +0.6V)→5.5V
Load regulation	Reg I _O	-	25	75	mV	I _O =0→0.5A
Minimum dropout Voltage	V _{CO}	-	0.4	0.6	V	V _{CC} =3.3V, I _O =0.5A
Output reference voltage	V _{FB}	0.792	0.800	0.808	V	I _O =0mA
EN Low voltage	V _{EN} (Low)	0	-	0.8	V	
EN High voltage	V _{EN} (High)	2.4	-	5.5	V	
EN Bias current	I _{EN}	1	3	9	μA	

●I/O Equivalent circuits



●Reference Data (Unless otherwise noted, $T_a=25^\circ\text{C}$, $EN=3\text{V}$, $V_{cc}=3.3\text{V}$, $R_1=16\text{k}\Omega$, $R_2=7.5\text{k}\Omega$)

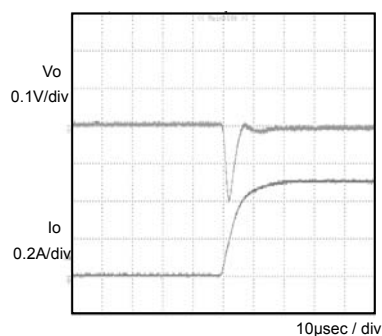


Fig.1 Transient response(0→1.0A)
 $C_o=1\mu\text{F}$

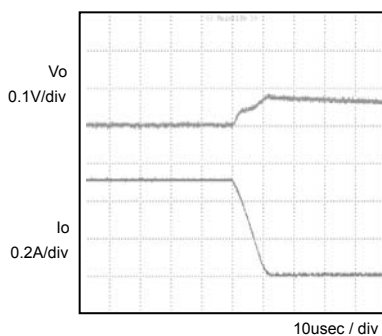


Fig.2 Transient response (1.0→0A)
 $C_o=1\mu\text{F}$

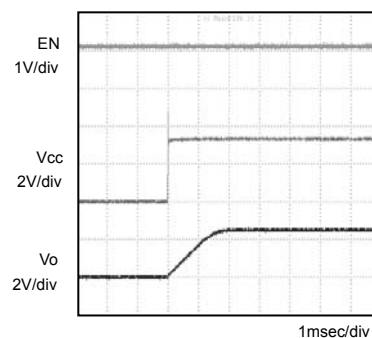


Fig.3 Input sequence 1
 $C_o=1\mu\text{F}$

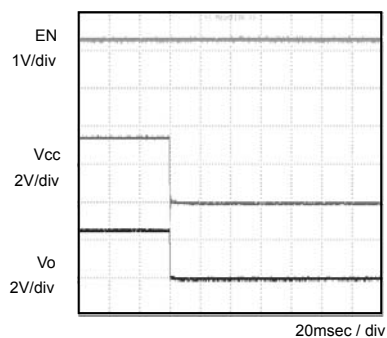


Fig.4 OFF sequence 1
 $C_o=1\mu\text{F}$

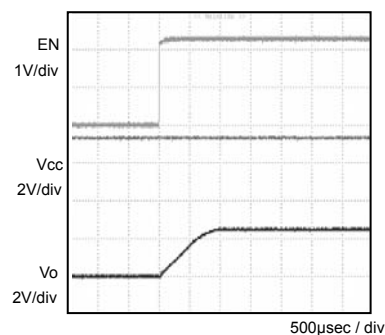


Fig.5 Input sequence 2
 $C_o=1\mu\text{F}$

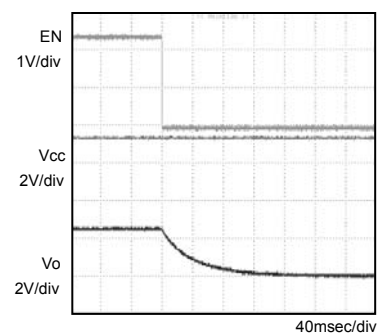


Fig.6 OFF sequence 2
 $C_o=1\mu\text{F}$

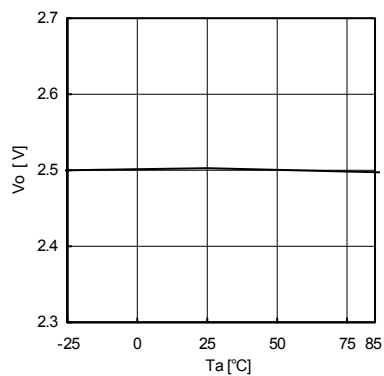


Fig.7 T_a - V_o ($I_o=0\text{mA}$)

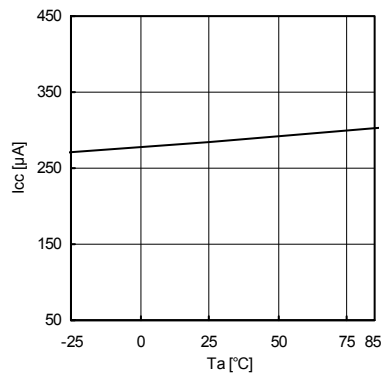


Fig.8 T_a - I_{cc}

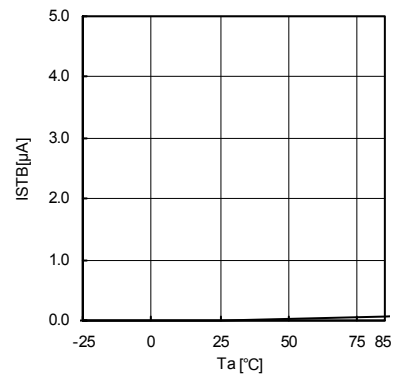


Fig.9 T_a - I_{std}
($V_{EN}=0\text{V}$)

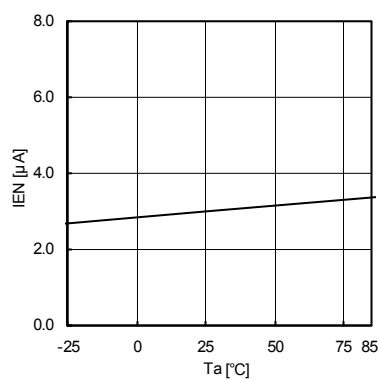


Fig.10 T_a - I_{EN}

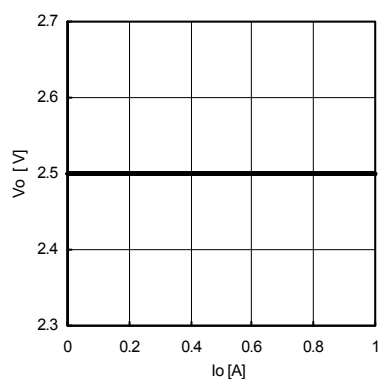


Fig.11 I_o - V_o

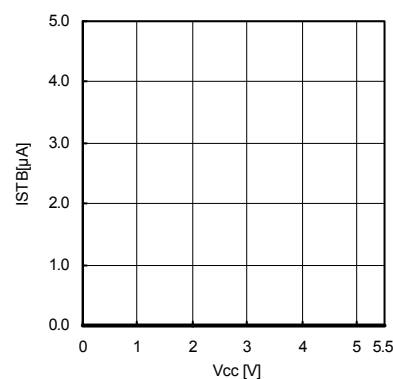


Fig.12 V_{cc} - I_{std}
($V_{EN}=0\text{V}$)

●Reference Data

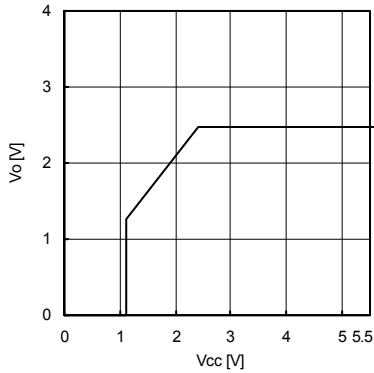
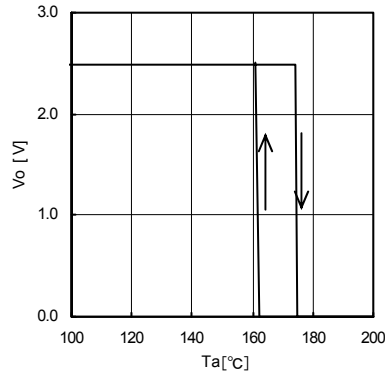
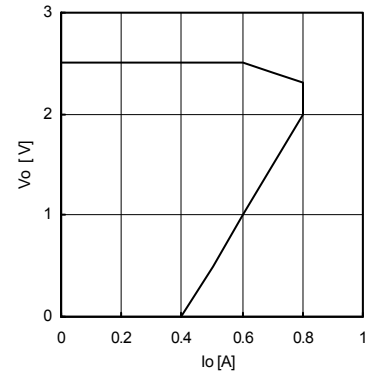
Fig.13 V_{cc} - V_o ($I_o=0\text{mA}$)Fig.14 TSD ($I_o=0\text{mA}$)

Fig.15 OCP

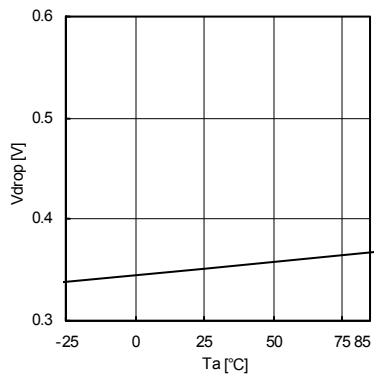
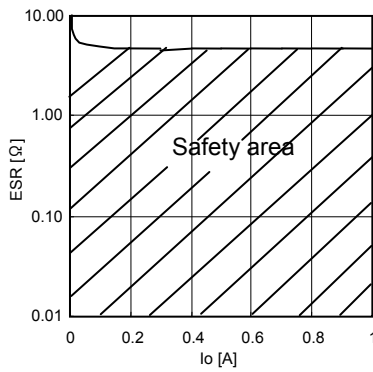
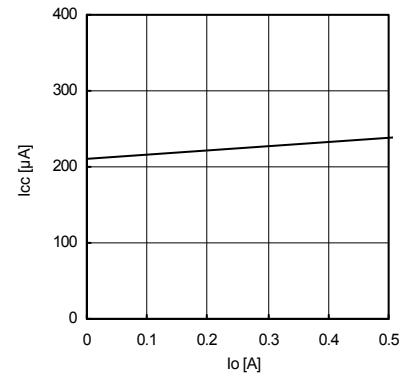
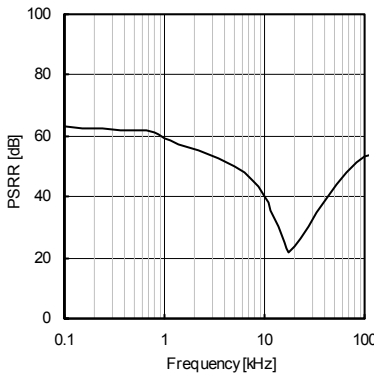
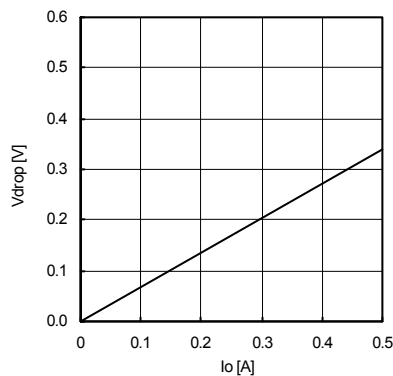
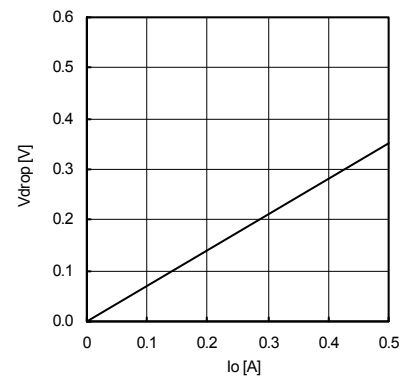
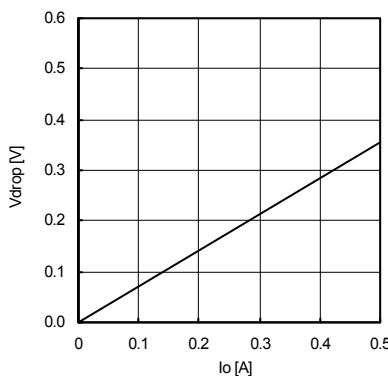
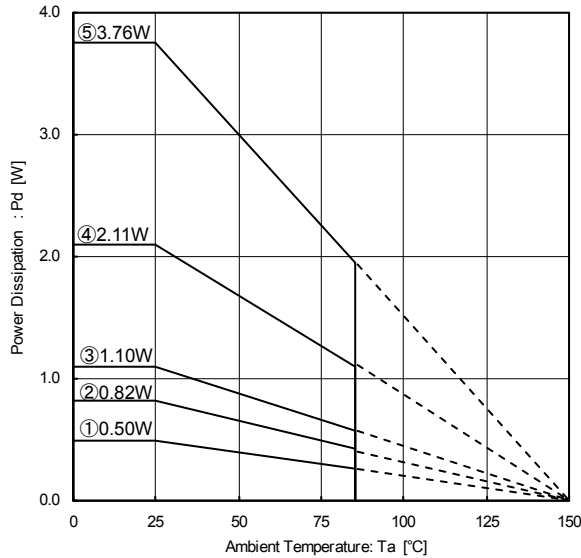
Fig.16 Minimum dropout Voltage 1
($V_{cc}=3.3\text{V}$, $I_o=-0.5\text{A}$)

Fig.17 ESR Condenser

Fig.18 I_o - I_{cc} Fig.19 PSRR ($I_o=0\text{mA}$)Fig.20 Minimum dropout Voltage 2
($V_{cc}=2.4\text{V}$, $T_a=25^\circ\text{C}$)Fig.21 Minimum dropout Voltage 3
($V_{cc}=3.3\text{V}$, $T_a=25^\circ\text{C}$)Fig.22 Minimum dropout Voltage 4
($V_{cc}=5.0\text{V}$, $T_a=25^\circ\text{C}$)

●Heat Dissipation Characteristics

◎HTSOP-J8



Measure condition: mounted on a ROHM board, and IC
Substrate size: 70mm × 70mm × 1.6mm
(Substrate with thermal via)

• Solder the substrate and package reverse exposure heat radiation part

- ① IC only
 $\theta_{j-a}=249.5^{\circ}\text{C/W}$
- ② 1-layer(copper foil are :0mm × 0mm)
 $\theta_{j-a}=153.2^{\circ}\text{C/W}$
- ③ 2-layer(copper foil are :15mm × 15mm)
 $\theta_{j-a}=113.6^{\circ}\text{C/W}$
- ④ 2-layer(copper foil are :70mm × 70mm)
 $\theta_{j-a}=59.2^{\circ}\text{C/W}$
- ⑤ 4-layer(copper foil are :70mm × 70mm)
 $\theta_{j-a}=33.3^{\circ}\text{C/W}$

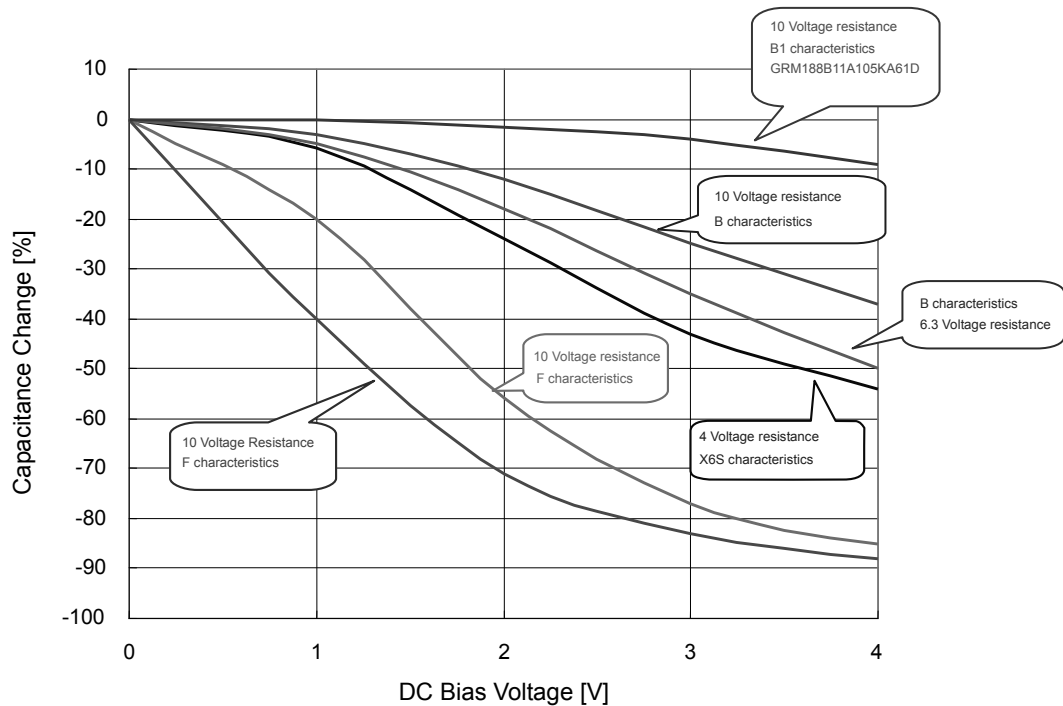
●About Input-to-output capacitor

It is recommended that a capacitor is placed nearby pin between Input pin and GND, output pin and GND.

A capacitor, between input pin and GND, is valid when the power supply impedance is high or drawing is long. Also as for a capacitor, between output pin and GND, the greater the capacity, more sustainable the line regulation and it makes improvement of characteristics by load change. However, please check by mounted on a board for the actual application. Ceramic capacitor usually has difference, thermal characteristics and series bias characteristics, and moreover capacity decreases gradually by using conditions.

For more detail, please be sure to inquire the manufacturer, and select the best ceramic capacitor.

Ceramic capacitor capacity- DC bias characteristics
(Characteristics example)



●Heat Loss

Thermal design should allow operation within the following conditions. Note that the temperatures listed are the allowed temperature limits, and thermal design should allow sufficient margin from the limits.

1. Ambient temperature T_a can be no higher than 85°C.
2. Chip junction temperature (T_j) can be no higher than 150°C.

Chip junction temperature can be determined as follows:

① Calculation based on ambient temperature (T_a)

$$T_j = T_a + \theta_{j-a} \times W$$

<Reference values>

θ_{j-a} : HTSOP-J8	153.2°C/W	1-layer substrate (copper foil density 0mm × 0mm)
	113.6°C/W	2-layer substrate (copper foil density 15mm × 15mm)
	59.2°C/W	2-layer substrate (copper foil density 70mm × 70mm)
	33.3°C/W	4-layer substrate (copper foil density 70mm × 70mm)

Substrate size: 70 × 70 × 1.6mm³ (substrate with thermal via)

Most of the heat loss that occurs in the BD00IA5WEFJ is generated from the output Pch FET. Power loss is determined by the total V_{CC} - V_o voltage and output current. Be sure to confirm the system input and output voltage and the output current conditions in relation to the heat dissipation characteristics of the V_{IN} and V_o in the design. Bearing in mind that heat dissipation may vary substantially depending on the substrate employed (due to the power package incorporated in the BD00IA5WEFJ make certain to factor conditions such as substrate size into the thermal design.

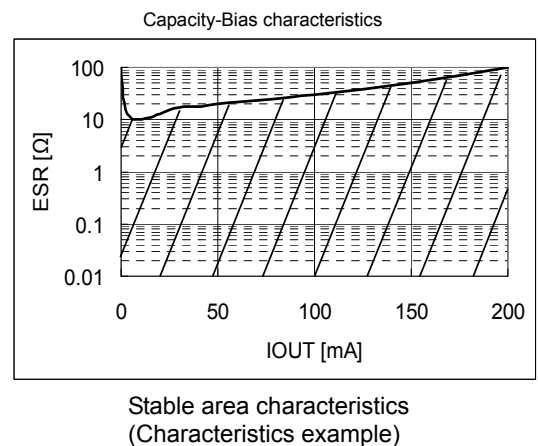
$$\text{Power consumption (W)} = \left\{ \text{Input voltage (VCC)} - \text{Output voltage (Vo)} \right\} \times I_o(\text{Ave})$$

Example) Where $V_{CC}=3.3\text{V}$, $V_o=2.5\text{V}$, $I_o(\text{Ave}) = 0.1\text{A}$,

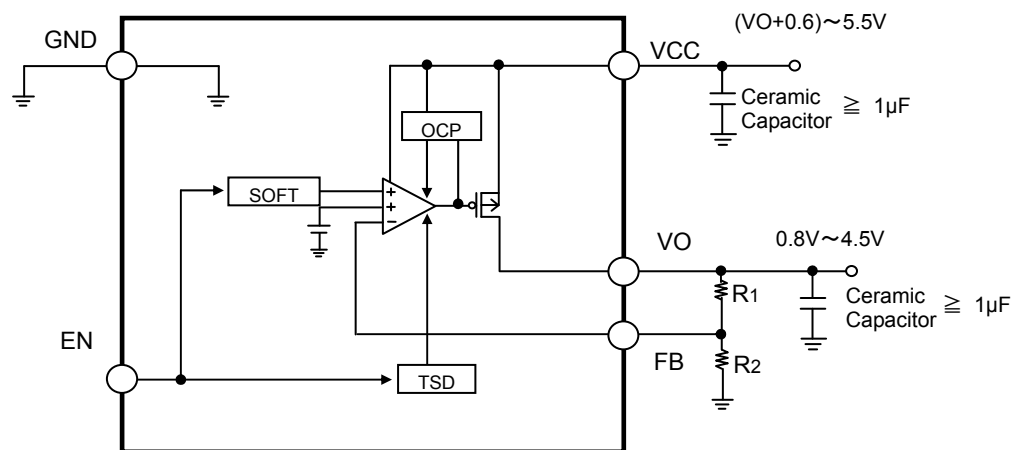
$$\begin{aligned} \text{Power consumption (W)} &= \left\{ 3.3(\text{V}) - 2.5(\text{V}) \right\} \times 0.1(\text{A}) \\ &= 0.08(\text{W}) \end{aligned}$$

●About equivalent series resistance ESR (ceramic capacitor etc.)

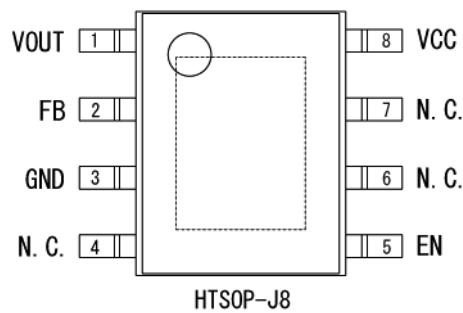
Capacitor usually has ESR(Equivalent Series Resistance), and operates stable in ESR-OUT range, showed right. Generally, ESR of ceramic, tantalum and electronic capacitor etc. is different for each, so please be sure to check a capacitor which is going to use, and use it inside the stable range, showed right. Then, please evaluate for the actual application



●Block Diagram
BD00IA5WEFJ

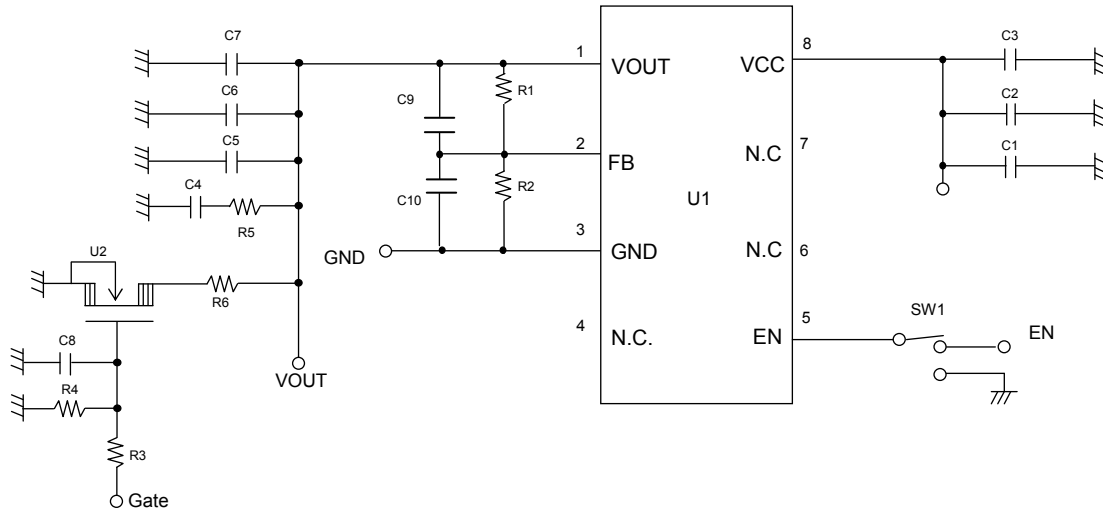


●Pin number, Pin name



Pin No.	Pin name	Pin Function
1	VOUT	Output voltage pin
2	FB	Feedback pin
3	GND	GND pin
4	N.C.	Non Connection
5	EN	Enable pin
6	N.C.	Non Connection
7	N.C.	Non Connection
8	VCC	Input voltage pin
Reverse	FIN	Substrate(GND pin)

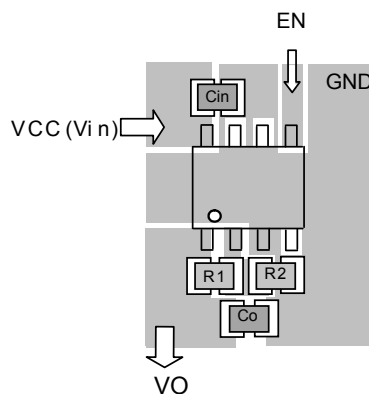
●Evaluation board circuit



●Evaluation board parts list

Designation	Value	Part No.	Company	Designation	Value	Part No.	Company
R1	16k Ω	MCR01PZPZF1602	ROHM	C4	-	-	-
R2	7.5k Ω	MCR01PZPZF7501	ROHM	C5	1 μ F	CM105B105K16A	KYOCERA
R3	-	-	-	C6	-	-	-
R4	-	-	-	C7	-	-	-
R5	-	-	-	C8	-	-	-
R6	-	-	-	C9	-	-	-
C1	1 μ F	CM105B105K16A	KYOCERA	C10	-	-	-
C2	-	-	-	U1	-	BD00IA5WEFJ	ROHM
C3	-	-	-	U2	-	-	-

●About Board Layout



- Input capacitor C_{in} of VCC (V_{in}) should be placed very close to VCC(V_{in}) pin as possible, and used broad wiring pattern. Output capacitor C_o also should be placed close to IC pin as possible. In case connected to inner layer GND plane, please use several through hole.
- VFB pin has comparatively high impedance, and is apt to be effected by noise, so floating capacity should be minimum as possible. Please be careful in wiring drawing
- Please take GND pattern space widely, and design layout to be able to increase radiation efficiency.
- For output voltage setting
Output voltage can be set by FB pin voltage(0.800V typ.)and external resistance R1, R2.

$$VO = V_{FB} \times \frac{R1+R2}{R2}$$

(The use of resistors with $R1+R2=5k$ to $90k$ is recommended)

●Notes for use

(1) Absolute maximum ratings

An excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down the devices, thus making impossible to identify breaking mode, such as a short circuit or an open circuit. If any over rated values will expect to exceed the absolute maximum ratings, consider adding circuit protection devices, such as fuses.

(2) Connecting the power supply connector backward

Connecting of the power supply in reverse polarity can damage IC. Take precautions when connecting the power supply lines. An external direction diode can be added.

(3) Power supply lines

Design PCB layout pattern to provide low impedance GND and supply lines. To obtain a low noise ground and supply line, separate the ground section and supply lines of the digital and analog blocks. Furthermore, for all power supply terminals to ICs, connect a capacitor between the power supply and the GND terminal. When applying electrolytic capacitors in the circuit, not that capacitance characteristic values are reduced at low temperatures.

(4) GND voltage

The potential of GND pin must be minimum potential in all operating conditions.

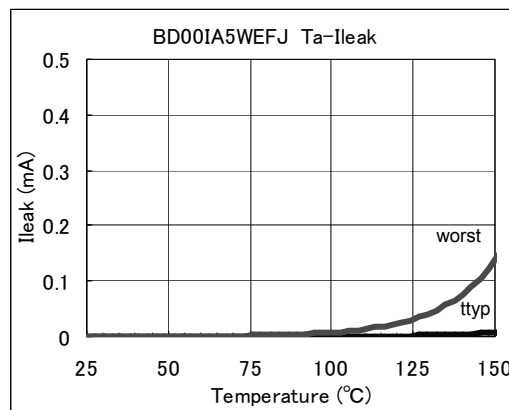
(5) Thermal design

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

(6) Off leak in high temperature.

Off-leak in high temperature may increase because of manufacturing of IC diviation.

Design in consideration with graph of typ, worst is shown below.



(7) Inter-pin shorts and mounting errors

Use caution when positioning the IC for mounting on printed circuit boards. The IC may be damaged if there is any connection error or if pins are shorted together.

(8) Actions in strong electromagnetic field

Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.

(9) ASO

When using the IC, set the output transistor so that it does not exceed absolute maximum ratings or ASO.

(10) Thermal shutdown circuit

The IC incorporates a built-in thermal shutdown circuit (TSD circuit). The thermal shutdown circuit (TSD circuit) is designed only to shut the IC off to prevent thermal runaway. It is not designed to protect the IC or guarantee its operation. Do not continue to use the IC after operating this circuit or use the IC in an environment where the operation of this circuit is assumed.

	TSD ON Temperature[°C] (typ.)	Hysteresis Temperature [°C] (typ.)
BD00IA5WEFJ	175	15

(11) Testing on application boards

When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process. Ground the IC during assembly steps as an antistatic measure. Use similar precaution when transporting or storing the IC.

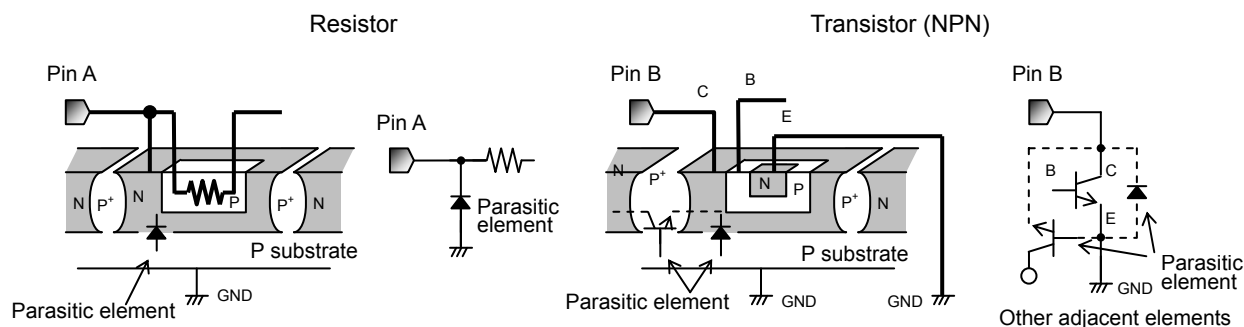
(12) Regarding input pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of these P layers with the N layers of other elements, creating a parasitic diode or transistor. For example, the relation between each potential is as follows:

When $GND > Pin A$ and $GND > Pin B$, the P-N junction operates as a parasitic diode.

When $GND > Pin B$, the P-N junction operates as a parasitic transistor.

Parasitic diodes can occur inevitable in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Accordingly, methods by which parasitic diodes operate, such as applying a voltage that is lower than the GND (P substrate) voltage to an input pin, should not be used.



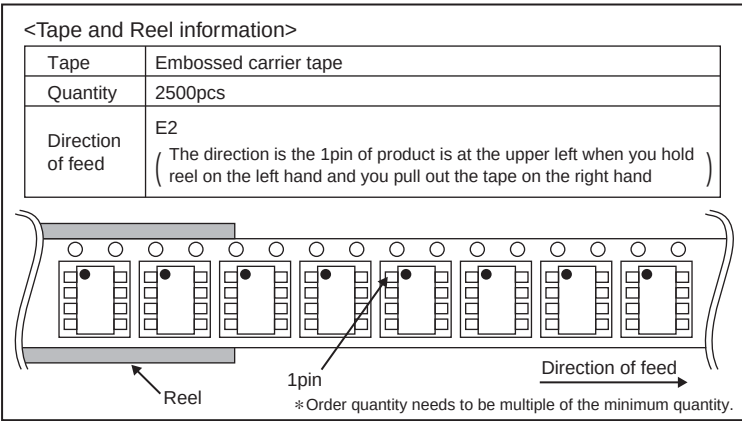
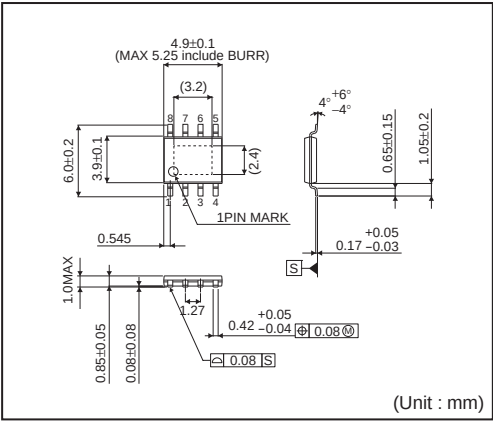
(13) Ground Wiring Pattern.

When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the ground potential of application so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring pattern of any external components, either.

●Ordering part number

B	D	0	0	I	A	5	W	E	F	J	-	E	2
ROHM Part Number		Output voltage 00 : Variable		Voltage resistance E :24V F :20V G :15V H :10V I :7V		Output cuurent A1:0.1A A3:0.3A A5:0.5A C0:1.0A C5:1.5A D0:2.0A		Shutdown switch "W" : Built in " " : None		Package EFJ : HTSOP-J8		Packaging specifications E2: Emboss tape reel	

HTSOP-J8



Notes

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